## OP \$440.00 613649

### PATENT ASSIGNMENT

## Electronic Version v1.1 Stylesheet Version v1.1

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

### **CONVEYING PARTY DATA**

Name	Execution Date
REPLISAURUS TECHNOLOGIES AB	11/04/2010
REPLISAURUS TECHNOLOGIES INC	11/04/2010

### RECEIVING PARTY DATA

Name:	REPLISAURUS GROUP SAS
Street Address:	Le Soleil Levant, Immeuble Sendai 11, chemin des Anciennes Vignes
City:	69410 Champagne au Mont d'Or
State/Country:	FRANCE

### PROPERTY NUMBERS Total: 11

Property Type	Number
Application Number:	61364989
Application Number:	12085176
Application Number:	12085157
Application Number:	12094142
Application Number:	12412319
Application Number:	12470448
Application Number:	12801219
Application Number:	12412322
Application Number:	12470452
Application Number:	12470444
Patent Number:	7790009

### **CORRESPONDENCE DATA**

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Correspondence will be sent via US Mail when the fax attempt is unsuccessful.

Email: james.stein@finnegan.com

**PATENT** 

REEL: 025471 FRAME: 0532

Correspondent Name: FINNEGAN, HENDERSON, FARABOW, GARRETT &

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ATTORNEY DOCKET NUMBER: 10760.0001, 02, 03, 04,60

NAME OF SUBMITTER: Veronica Bayne

**Total Attachments: 5** 

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			ECORDATION FORM COVE PATENTS ONLY	Patent and Trademark Office Attorney Docket No. 10760.0001, 0002, 0003, 0004, and 6000									
	ne Director of the U.S. Pa se record the attached o				Mail S	top Assignment R	ecordation Services						
1.	Name of conveying pa a) REPLISAURUS TE b) REPLISAURUS TE	arty(ies): ECHNOLOGIE	S AB	2. Name:		address of receiving							
Addit	ional name(s) of conveyin	g party(ies) at	ached?  Yes  No	Internal	Address:								
3.	Nature of conveyance	:		Street /		Le Soleil Levant, 11, chemin des Anciennes Vignes							
	Assignment	□ Me	erger	City:	69410 Chan FRANCE	npagne au Mont d	'Or,						
	Security Agreement	☐ CH	nange of Name	State:		Zip Code:							
	Joint Research Agreement	I —	overnment Interest signment	Addition	nal name(s) &	Address(es) attach	ed?						
	Executive Order 9494, Confirmatory License	☐ Ot	her:		☐ Yes	⊠ No							
Exec	ution Date: November	4, 2010											
4. A.	the application: Patent Application Nu	mber(s):	ber(s): If this document is be	eing filed together with a new application, the execution date o  B. Patent Number(s): 7,790,009									
	12/470,448; 12/801,21 12/470,444	19; 12/412,322	; 12/470,452; AND	7,790,009  ☐ Yes ⊠ No									
5.	Name and address of concerning document	party to whom should be mai	correspondence led:	6.	Total numbe 10 (Ten)	r of applications an	d patents involved:						
Name	e: Gerson S. Panitch		(202) 408-4000	7.	Total fee (37 \$440	CFR 1.21(h) and 3	3.41): <b>\$40 X 11 =</b>						
	& DUNNER		N, FARABOW, GARRETT		Enclose	d (Please charge d ment to deposit acc							
City:	Washington, l	D.C.			Authoriz	zed to be charged t	o deposit account						
State		Zip:	20001-4413	8.	Deposit Acco	ount No.: <u>06-0916</u>							
 9.	Statement and signatu	ıre.		<u> </u>									
To the	e best of my knowledge an	nd belief, the fo	oregoing information is true a	and correc	t and any atta	ched copy is a true	copy of the original						
	Signed:	10	me DH			December 1	0, 2010						
	Signed.		James D. Stein			Da	te						
	Total	number of pa	Reg. No. 63,782 ges including cover sheet, at	ttachment	s and docume	ents: -5-							

### **ASSIGNMENT**

On this day, the 4th of November 2010,

it is hereby declared that we have assigned to:

REPLISAURUS GROUP SAS Le Soleil Levant, Immeuble Sendaï 11, chemin des Anciennes Vignes 69410 Champagne au Mont d'Or, France

Our entire rights in and to all patent applications and patents - as per enclosure 1 - now registered with

REPLISAURUS TECHNOLOGIES AB Isafjordsgatan 22 B, 5v SE-164 40 KISTA Sweden

and

REPLISAURUS TECHNOLOGIES INC 1209 Orange Street **WILMINGTON, DE 19801** USA

as applicants.

4-11-2010
Place and date
DEDITORISMIC TROUBLES COME

4-11-2010

REPLISAURUS TECHNOLOGIES AB

REPLISAURUS TECHNOLOGIES INC

Signature of Assignor

nature of Assignor

BANIER CARL Name in block letters

DANIEL A. CARL Name in block letters

The above assignment is accepted.

REPLISAURUS GROUP SAS

Place and date

Signature of Assignee

Name in block letters

It is hereby certified they tro true and correct copy of the

document:

**PATENT** 

REEL: 025471 FRAME: 0535

P52190001 E52190001 E52190001CA P52190001CA P52190001HK P52190001HV P52190001HP	Sweden EPO Canada China Hong Kong India Japan Japan South Korea WSA USA USA USA USA	0102144-3 0102144-3 02739042.6 10182946.3 2,462,098 02811926.6 05104929.3 02129/DELNP/2003 2003-505393 2009-142804 2003-7016336 PI 20034732 1-2003-501274 2003136088 200307357-4 10/734 223 12/801 219 06813033.5 2008-541118 2008-541118 2008-7014730 12/085 176 12/085 176	523 309 523 309 5202811926.6 HK1072083 4546078 1-2003-501274 2296820 101 252	METHOD FOR DEFI METHOD OF FORMI METHOD OF FORMI METHOD OF FORMI METHOD OF FORMI
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_	ndia	02129/DELNP/2003		METHOD FOR DEFINING AND REPLICATING STRUCTURE IN CONDUCTING MATERIAL
	Japan	2003-505393	4546078	METHOD FOR DEFINING AND REPLICATING STRUCTURE IN CONDUCTING MATERIAL
	Japan	2009-142804		METHOD FOR DEFINING AND REPLICATING STRUCTURE IN CONDUCTING MATERIAL
	South Korea	2003-7016336		METHOD FOR DEFINING AND REPLICATING STRUCTURE IN CONDUCTING MATERIAL
	Malaysia	PI 20034732		METHOD FOR DEFINING AND REPLICATING STRUCTURE IN CONDUCTING MATERIAL
	Philippines	1-2003-501274	1-2003-501274	METHOD FOR DEFINING AND REPLICATING STRUCTURE IN CONDUCTING MATERIAL
	Russia	2003136088	2296820	METHOD FOR DEFINING AND REPLICATING STRUCTURE IN CONDUCTING MATERIAL
	Singapore	200307357-4	101 252	METHOD FOR DEFINING AND REPLICATING STRUCTURE IN CONDUCTING MATERIAL
	USA	10/734 223		METHOD FOR DEFINING AND REPLICATING STRUCTURE IN CONDUCTING MATERIAL
	USA	12/801 219		METHOD FOR DEFINING AND REPLICATING STRUCTURE IN CONDUCTING MATERIAL
	EPO	06813033.5		METHOD OF FORMING A MULTILAYER STRUCTURE
	China	200680051024.3		METHOD OF FORMING A MULTILAYER STRUCTURE
	Japan	2008-541118		METHOD OF FORMING A MULTILAYER STRUCTURE
	South Korea	2008-7014730		METHOD OF FORMING A MULTILAYER STRUCTURE
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# Patent applications as per November 4, 2010

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Sweden	Sweden	Sweden	Sweden	USA	Sweden	Taiwan	РСТ	USA	South Korea	Japan	China	E P O	USA	USA	USA	USA	Sydkorea	Japan	China	EPO
1050799-4	1050798-6	1050797-8	1050796-0	61/364 989	1050795-2	98131796	PCT/EP2008/009658	12/094 142	2008-7014735	2008-541120	200680051055.9	06813034.3	12/470 444	12/470 452	12/470 448	12/085 157	2008-7014733	2008-541119	200680051145.8	06824464.9
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1050800-0

FILLING OF A PRINTING CHAMBER AND A CHUCK THEREFORE

REPLISAURUS TECHNOLOGIES AB

RINSING/DRYING - METHOD FOR RINSING AND/OR DRYING AN ECPR CHAMBER, AND CHUCKS REPLISAURUS TECHNOLOGIES AB

DEVICE, SYSTEM AND METHOD FOR USE IN MACHINES FOR ELECTROCHEMICAL PATTERN REP REPLISAURUS TECHNOLOGIES AB

METHOD AND SYSTEM FOR DETECTING, SETTING AND MONITORING THE SPATIAL SITUATION REPLISAURUS TECHNOLOGIES AB

P52190015

1050803-4

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Sweden

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P52190013

Sweden

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Page 3 of 3

It is hereby certified that this is a true and correct copy of the original document:

**RECORDED: 12/10/2010**